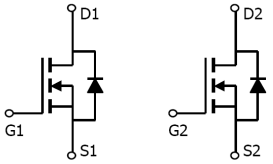
Feature

- 60V,7A
  $R_{DS(ON)}$ <20mΩ @V_{GS}=10V TYP:15 mΩ
  $R_{DS(ON)}$ <25mΩ @V_{GS}=4.5V TYP:19 mΩ
- Trench DMOS Power MOSFET
- Fast Switching
- Exceptional on-resistance and maximum DC current capability



Schematic diagram



Marking and pin assignment

Application

- DC/DC Converter
- Load Switch for Portable Devices
- Battery Switch

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
4846	AP4846	SOP-8	13 inch	-	4000

ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current (T_a =25℃)	I_D	7	A
Continuous Drain Current (T_a =100℃)	I_D	5.4	A
Pulsed Drain Currenr (1)	I_{DM}	28	A
Power Dissipation	P_D	2	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	62.5	℃/W
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-55~ +150	℃

MOSFET ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise noted)

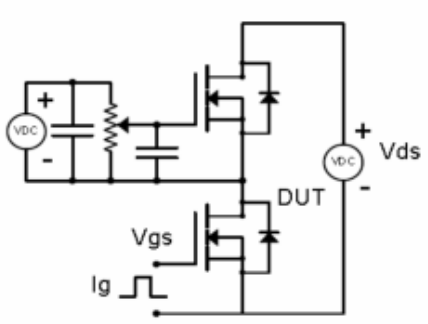
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D =250μA	60	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS} =60V, V_{GS} = 0V	-	-	1	μA
Gate-body leakage current	I_{GSS}	V_{GS} =±20V, V_{DS} = 0V	-	-	±100	nA
Gate threshold voltage(2)	$V_{GS(th)}$	V_{DS} =V_{GS}, I_D =250μA	1	1.6	2.5	V
Drain-source on-resistance(2)	$R_{DS(on)}$	V_{GS} =10V, I_D =7A	-	15	20	mΩ
		V_{GS} =4.5V, I_D =5A	-	19	25	
Dynamic characteristics						
Input Capacitance	C_{iss}	V_{DS} =25V, V_{GS} =0V, f =1MHz	-	2600	-	pF
Output Capacitance	C_{oss}		-	125	-	
Reverse Transfer Capacitance	C_{rss}		-	105	-	
Switching characteristics						
Turn-on delay time	$t_{d(on)}$	V_{DD}=30V，ID=7A V_{GS}=10V, R_G=6Ω	-	4	-	ns
Turn-on rise time	t_r		-	8	-	
Turn-off delay time	$t_{d(off)}$		-	27	-	
Turn-off fall time	t_f		-	20	-	
Total Gate Charge	Qg	VDS=30V,ID=7A VGS=10V	-	51	-	nC
Gate-Source Charge	Qgs		-	8	-	
Gate-Drain Charge	Qgd		-	8	-	
Source-Drain Diode characteristics						
Diode Forward voltage(2)	V_{DS}	V_{GS} =0V, I_S=5A	-	-	1.2	V
Diode Forward current(3)	I_S		-	-	7	A
Reverse recovery time	Trr	Is=7A,V_{GS}=0V,dI_F/dt=100A/us		21		ns
Reverse recovery charge	Qrr	Is=7A,V_{GS}=0V,dI_F/dt=100A/us		18		nC

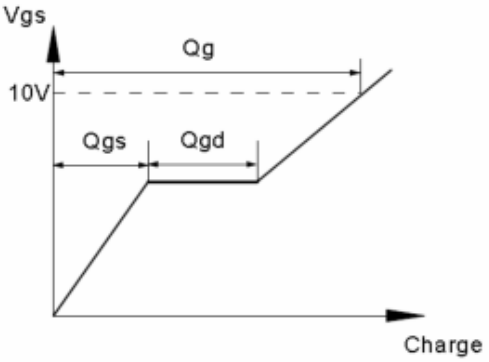
Notes:

1. Repetitive Rating: pulse width limited by maximum junction temperature
2. Pulse Test: pulse width≤300μs, duty cycle≤2%
3. Surface Mounted on FR4 Board,t≤10 sec

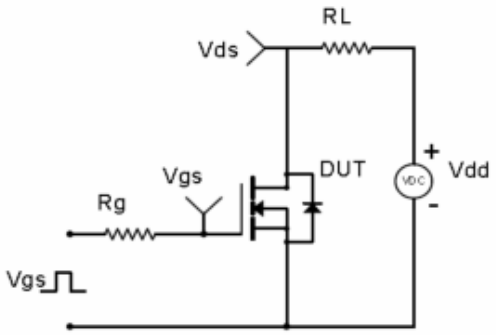
Test Circuit & Waveform

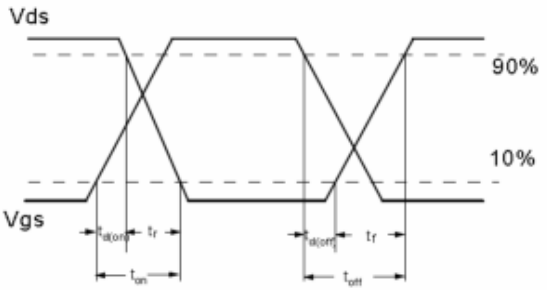
Gate Charge Test Circuit & Waveform



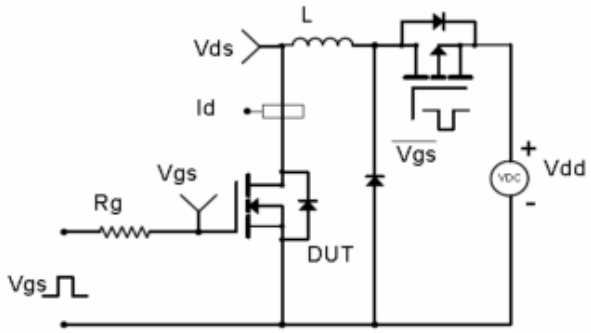


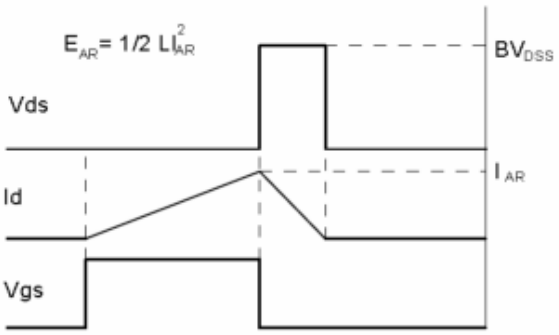
Resistive Switching Test Circuit & Waveforms



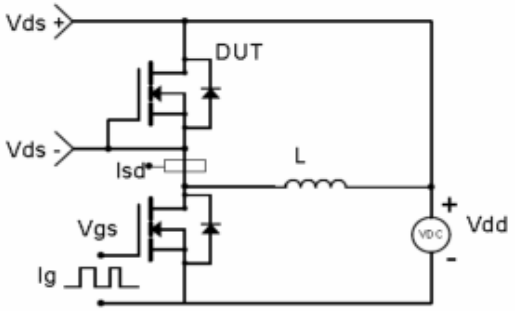


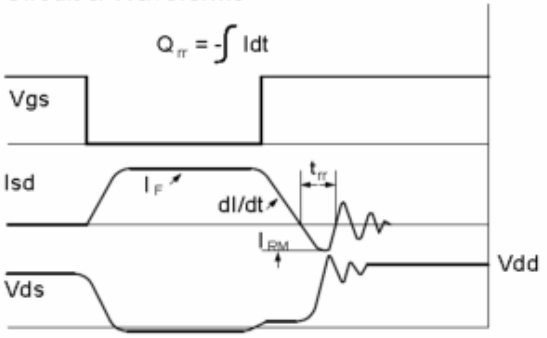
Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





Diode Recovery Test Circuit & Waveforms





Typical Characteristics (@ T_J = 25°C, unless otherwise specified.)

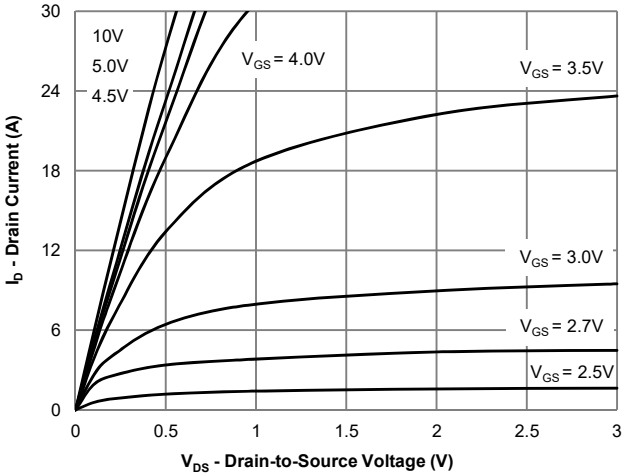


Figure 1: Output Characteristics

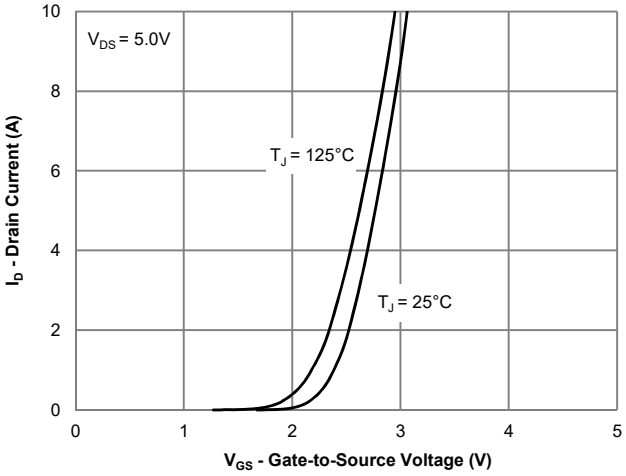


Figure 2: Transfer Characteristics

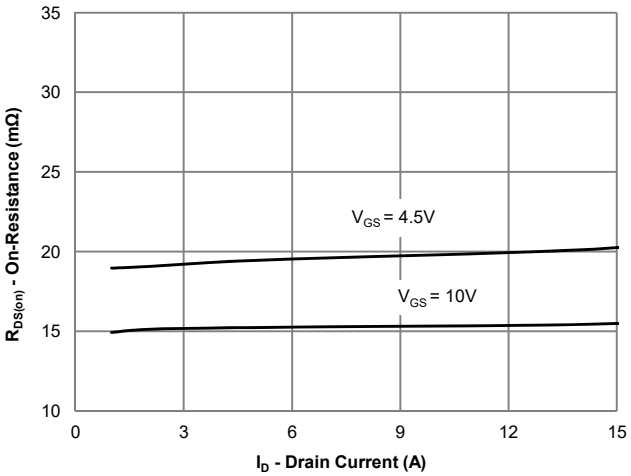


Figure 3: On-Resistance vs. Gate-Source Voltage

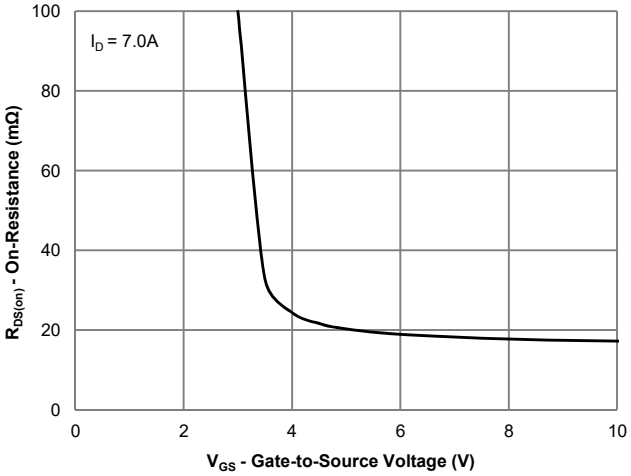


Figure 4: On-Resistance vs. Gate-Source Voltage

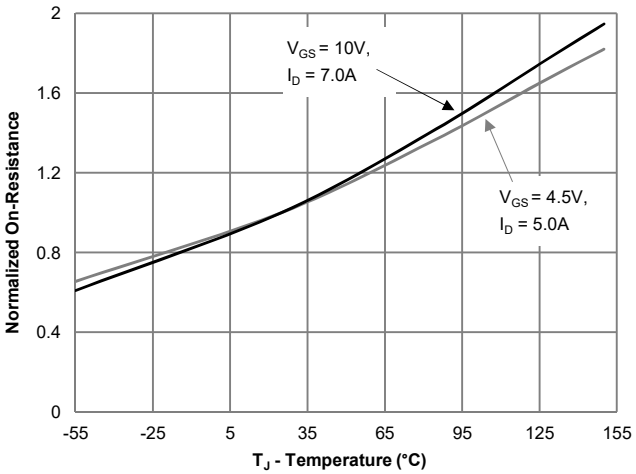


Figure 5: On-Resistance vs. Junction Temperature

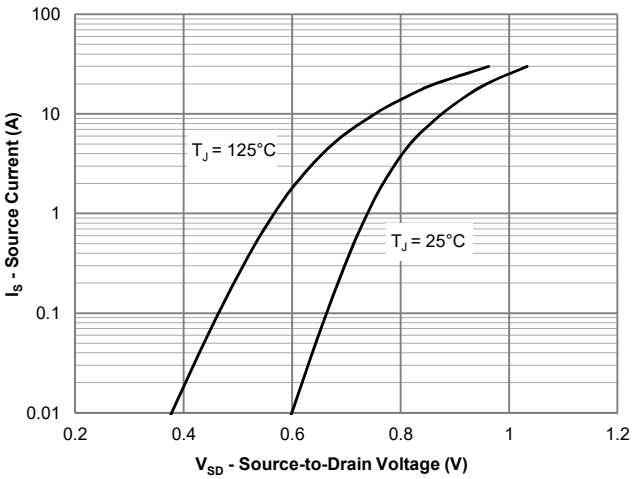


Figure 6: Source-Drain Diode Forward Voltage

Typical Characteristics (@ T_J = 25°C, unless otherwise specified.)

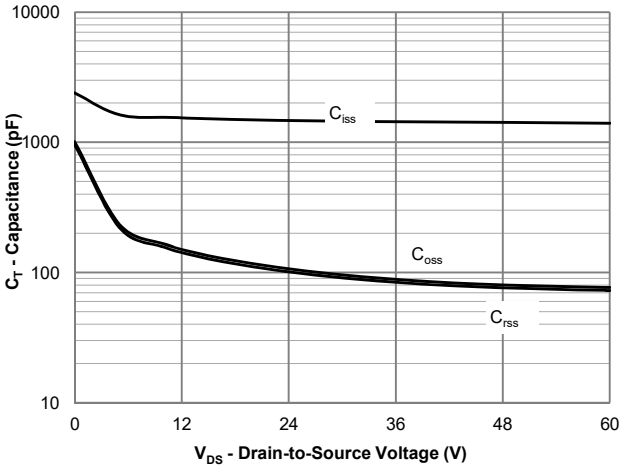


Figure 7: Capacitance Characteristics

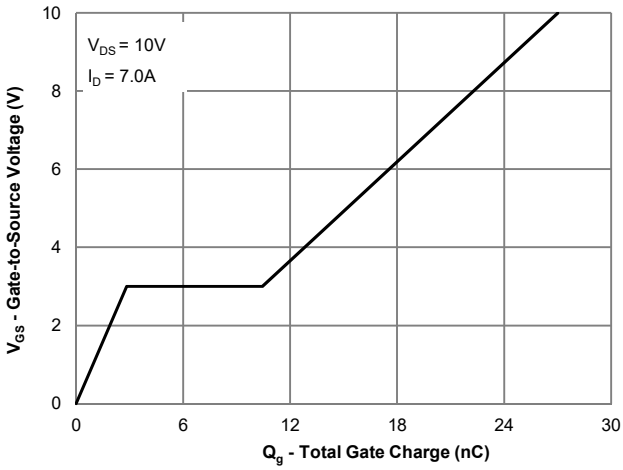


Figure 8: Gate Charge Characteristics

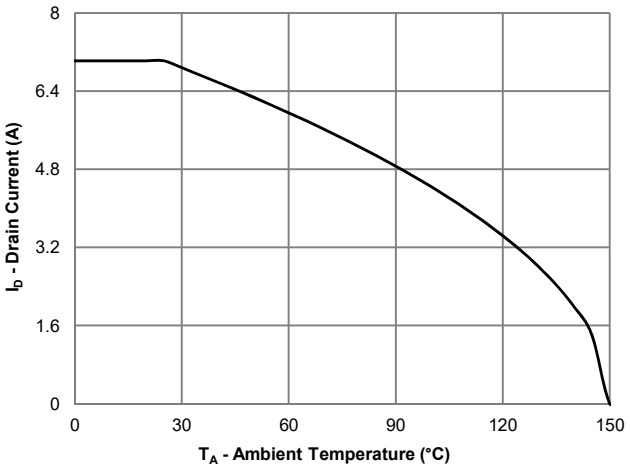


Figure 9: Current Derating

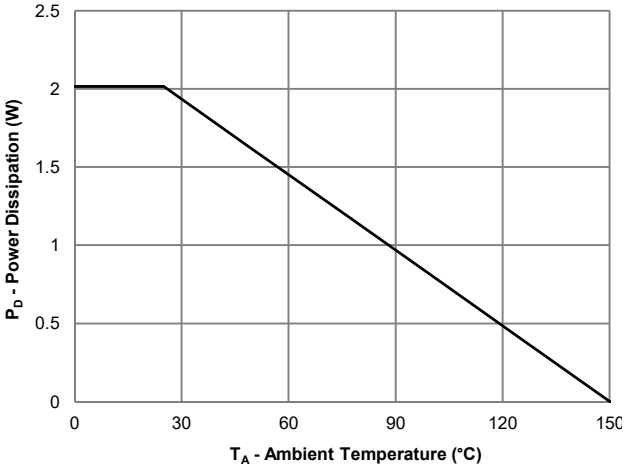


Figure 10: Power Derating

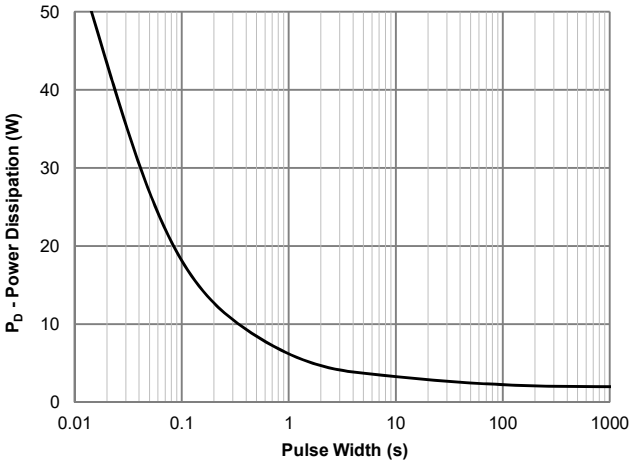


Figure 11: Single Pulse Power, Junction-to-Ambient

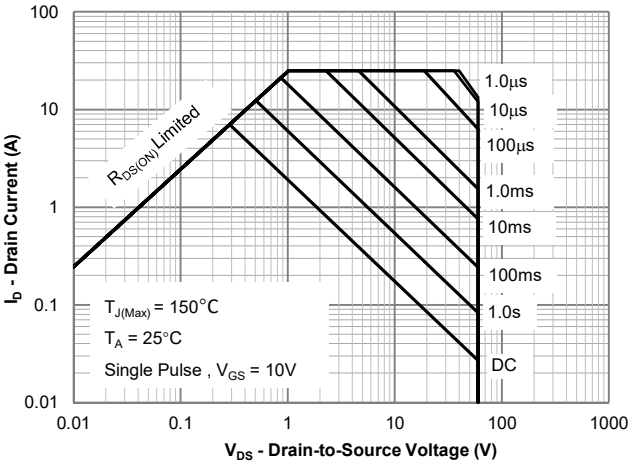


Figure 12: Safe Operating Area

Typical Characteristics (@ T_J = 25°C, unless otherwise specified.)

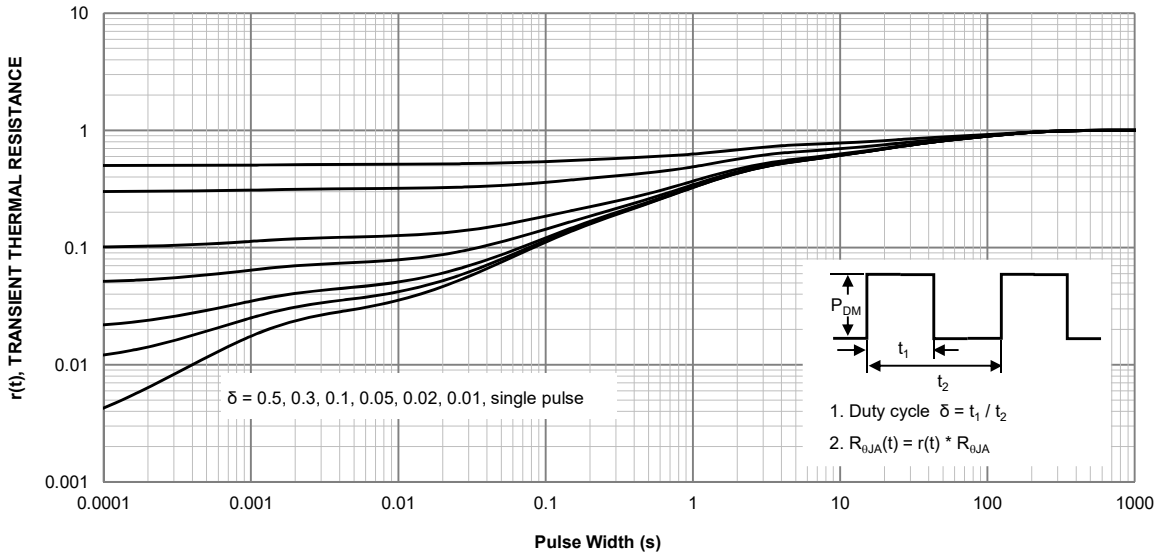
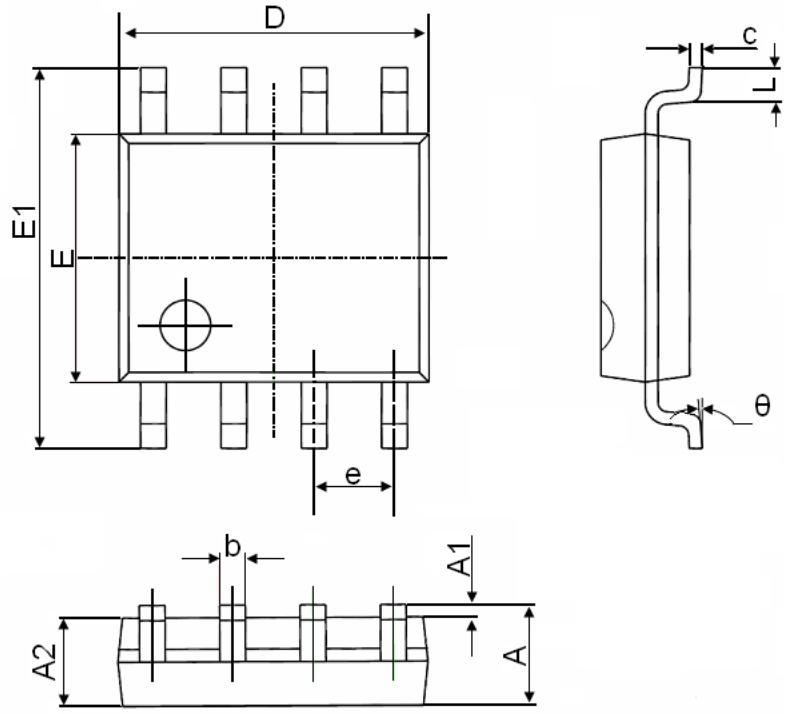


Figure 13: Normalized Thermal Transient Impedance

SOP-8 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

ALLPOWER assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.